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BYC10-600

WeEn Semiconductors

Rectifiers RAIL PN DIODE

Any questions, please feel free to contact us. info@kaimte.com





Product data sheet

1. General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- · Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

3. Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

4. Quick reference data

Symbol	Parameter	Conditions	Values				Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	600		V
$I_{F(AV)}$	average forward current	δ = 0.5; T _{mb} ≤ 78 °C; square-wave pulse; Fig. 1; Fig. 2			10		A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; T _{mb} ≤ 78 °C; square-wave pulse	20		A		
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	65			А	
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	71			А	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 10 A; T _j = 150 °C; <u>Fig. 4</u>	- 1.4 1.8		V		
Dynamic	characteristics	· · · · · · · · · · · · · · · · · · ·					
t _{rr}	reverse recovery time	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_i = 25 \text{ °C}; Fig. 6$		-	19	-	ns

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	А	anode	۲ O f	К <u>— Ң</u> А 001ааа020
mb	mb	mounting base; connected to cathode	C	001aaa020

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BYC10-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59			

7. Marking

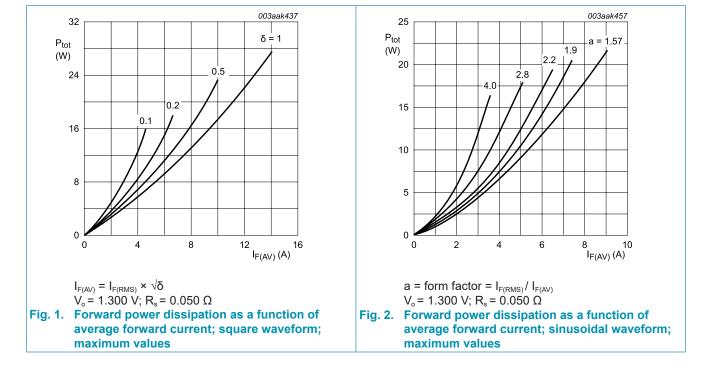
Table 4. Marking codes					
	Type number	Marking codes			
	BYC10-600	BYC10-600			

8. Limiting values

Table 5. Limiting values

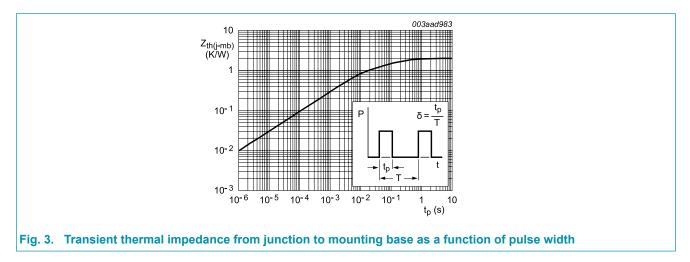
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V _{RRM}	repetitive peak reverse voltage		600	V
V _{RWM}	crest working reverse voltage		600	V
V _R	reverse voltage	T _{mb} ≤ 114 °C	500	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 78 °C; square-wave pulse; Fig. 1; Fig. 2	10	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; T _{mb} ≤ 78 °C; square-wave pulse	20	A
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	65	А
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	71	А
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C



9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 3</u>	-	-	2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

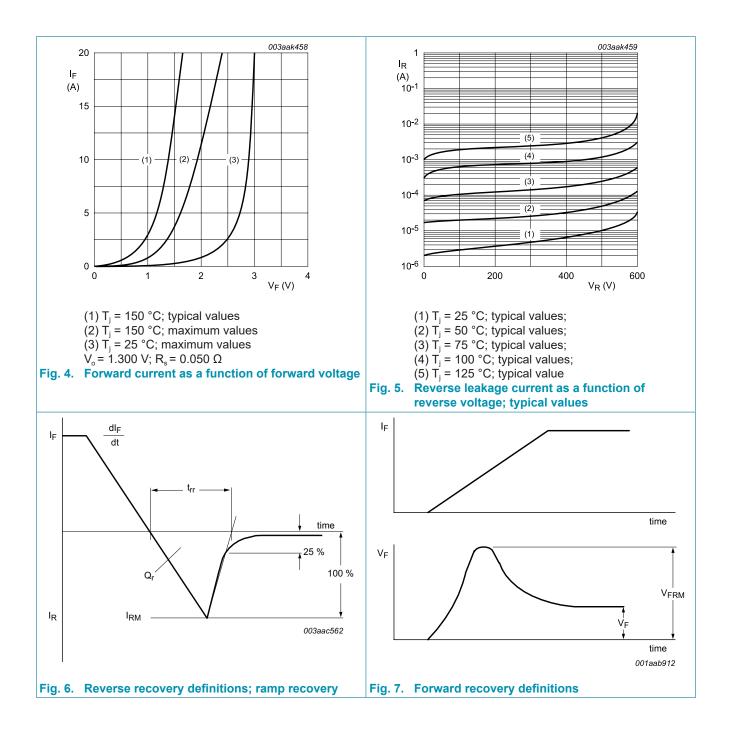


10. Characteristics

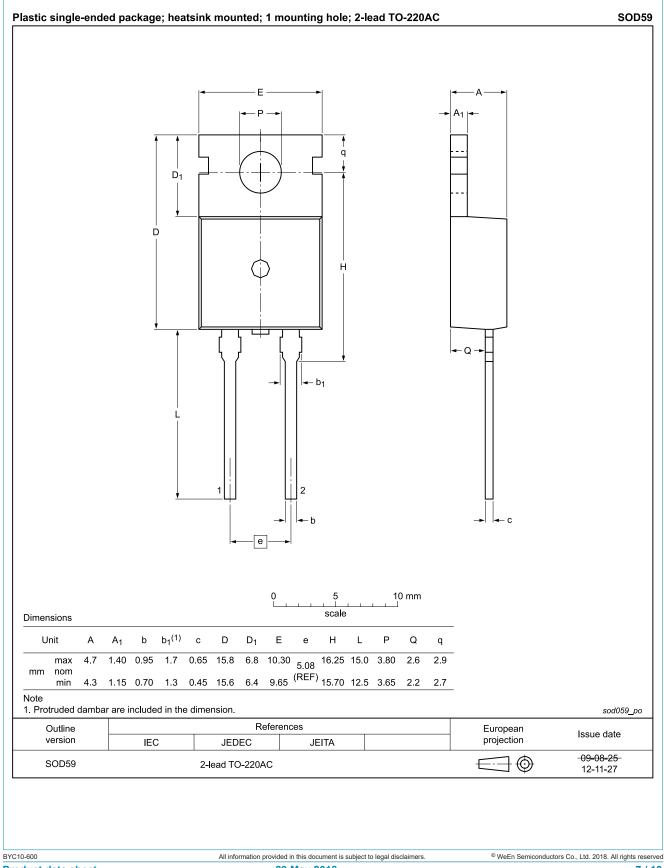
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics	· · · · · · · · · · · · · · · · · · ·			_	
V _F	forward voltage	I _F = 10A; T _j = 25 °C; <u>Fig. 4</u>	-	2	2.9	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 4</u>	-	1.4	1.8	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 4</u>	-	1.7	2.3	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C; <u>Fig. 5</u>	-	9	200	μA
		V _R = 500 V; T _j = 100 °C; <u>Fig. 5</u>	-	1.1	3	mA
Dynamic	characteristics	· · · · · · · · · · · · · · · · · · ·				
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 6}$	-	35	55	ns
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 ^\circ\text{C}; \text{ Fig. 6}$	-	19	-	ns
		$I_{F} = 10 \text{ A}; V_{R} = 400 \text{ V}; dI_{F}/dt = 500 \text{ A}/\mu\text{s}; \\ T_{j} = 100 ^{\circ}\text{C}; \overline{\text{Fig. 6}}$	-	32	40	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; \text{ Fig. 6}$	-	3	7.5	A
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; \text{ Fig. 6}$	-	9.5	12	A
V _{FRM}	forward recovery voltage	I _F = 10 A; dI _F /dt = 100 A/μs; T _j = 25 °C; Fig. 7	-	8	11	V

Hyperfast power diode

BYC10-600



11. Package outline



BYC10-600

Hyperfast power diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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